# NSN 5961-00-278-9639

Transistor - Page 1 of 1



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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.550 inches

# **Overall Height:**

0.300 inches

# **Overall Width:**

1.050 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact-darlington connected

## Electrode Internally-electrically Connected To Case:

Collector

**Mounting Method:** 

# Unthreaded hole

Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage, dc and 100.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, dc

## **Current Rating Per Characteristic:**

Between 0.50 amperes source cutoff current and 16.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: pnp

## Test Data Document:

07690-429561 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

2 pin and 1 case

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

A110a0